



(11) **EP 2 467 854 B8**

(12) **CORRECTED EUROPEAN PATENT SPECIFICATION**

(15) Correction information:
Corrected version no 1 (W1 B1)
Corrections, see
Bibliography INID code(s) 73

(51) Int Cl.:
G11C 16/16 ^(2006.01) **G11C 16/10** ^(2006.01)
G11C 16/34 ^(2006.01) **G11C 16/04** ^(2006.01)
G11C 11/56 ^(2006.01)

(48) Corrigendum issued on:
03.06.2015 Bulletin 2015/23

(86) International application number:
PCT/US2010/045744

(45) Date of publication and mention
of the grant of the patent:
25.02.2015 Bulletin 2015/09

(87) International publication number:
WO 2011/022386 (24.02.2011 Gazette 2011/08)

(21) Application number: **10745708.7**

(22) Date of filing: **17.08.2010**

(54) **SELECTIVE MEMORY CELL PROGRAM AND ERASE**

SELEKTIVES SPEICHERZELLENPROGRAMM UND LÖSCHUNG

PROGRAMMATION ET EFFACEMENT SELECTIFS DE CELLULE DE MEMOIRE

(84) Designated Contracting States:
AL AT BE BG CH CY CZ DE DK EE ES FI FR GB
GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO
PL PT RO SE SI SK SM TR

(30) Priority: **19.08.2009 US 544113**

(43) Date of publication of application:
27.06.2012 Bulletin 2012/26

(73) Proprietor: **SanDisk Technologies, Inc.**
Plano, TX 75024 (US)

(72) Inventors:
• **DONG, Yingda**
Milpitas
CA 95035 (US)

• **KUO, Tien-chien**
Milpitas
CA 95035 (US)
• **HEMINK, Gerrit Jan**
Milpitas
CA 95035 (US)

(74) Representative: **Tothill, John Paul**
Dehns
St Bride's House
10 Salisbury Square
London
EC4Y 8JD (GB)

(56) References cited:
US-A1- 2008 089 130 US-A1- 2008 094 901
US-A1- 2009 201 733

EP 2 467 854 B8

Note: Within nine months of the publication of the mention of the grant of the European patent in the European Patent Bulletin, any person may give notice to the European Patent Office of opposition to that patent, in accordance with the Implementing Regulations. Notice of opposition shall not be deemed to have been filed until the opposition fee has been paid. (Art. 99(1) European Patent Convention).
